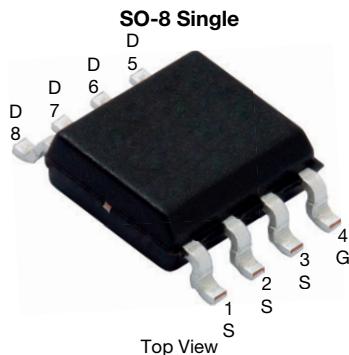
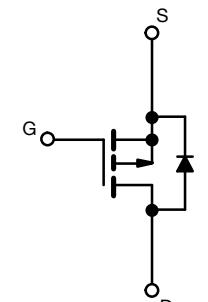


Automotive P-Channel 12 V (D-S) 175 °C MOSFET



FEATURES

- TrenchFET® power MOSFET
- AEC-Q101 qualified
- 100 % R_g and UIS tested
- Material categorization:
for definitions of compliance please see
www.vishay.com/doc?99912


RoHS
COMPLIANT
HALOGEN
FREE


P-Channel MOSFET

PRODUCT SUMMARY	
V_{DS} (V)	-12
$R_{DS(on)}$ (Ω) at $V_{GS} = -4.5$ V	0.00832
$R_{DS(on)}$ (Ω) at $V_{GS} = -2.5$ V	0.01000
$R_{DS(on)}$ (Ω) at $V_{GS} = -1.8$ V	0.01430
I_D (A)	-25
Configuration	Single

ORDERING INFORMATION	
Package	SO-8
Lead (Pb)-free and halogen-free	SQ4153EY (for detailed order number please see www.vishay.com/doc?79771)

ABSOLUTE MAXIMUM RATINGS ($T_C = 25$ °C, unless otherwise noted)			
PARAMETER	SYMBOL	LIMIT	UNIT
Drain-source voltage	V_{DS}	-12	
Gate-source voltage	V_{GS}	± 8	V
Continuous drain current ^a	I_D	-25	
		-14	
Continuous source current (diode conduction) ^a	I_S	-6.5	A
Pulsed drain current ^b	I_{DM}	-100	
Single pulse avalanche current	I_{AS}	-19	
Single pulse avalanche energy	E_{AS}	18	mJ
Maximum power dissipation ^b	P_D	7.1	W
		2.3	
Operating junction and storage temperature range	T_J, T_{stg}	-55 to +175	°C

THERMAL RESISTANCE RATINGS			
PARAMETER	SYMBOL	LIMIT	UNIT
Junction-to-ambient	R_{thJA}	85	°C/W
Junction-to-foot (drain)	R_{thJF}	21	

Notes

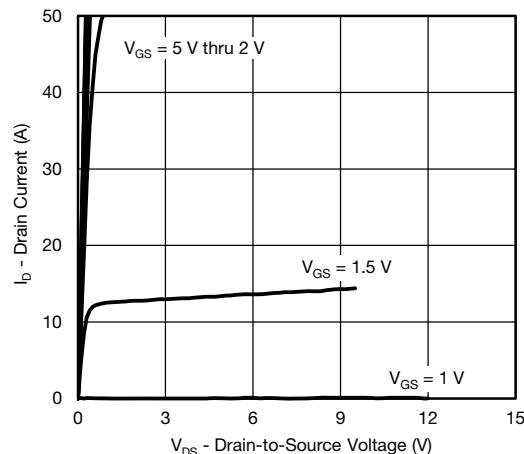
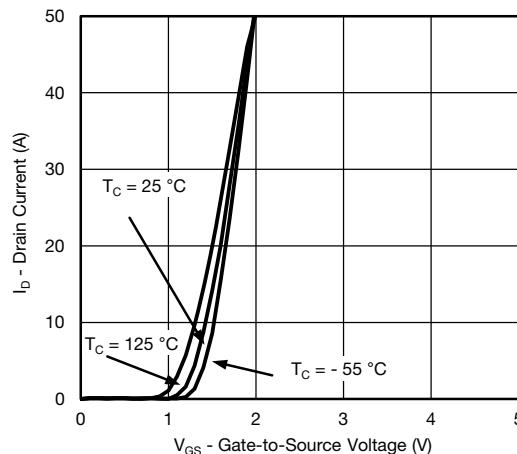
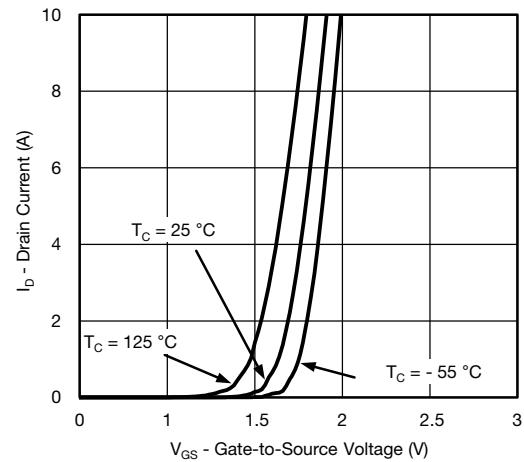
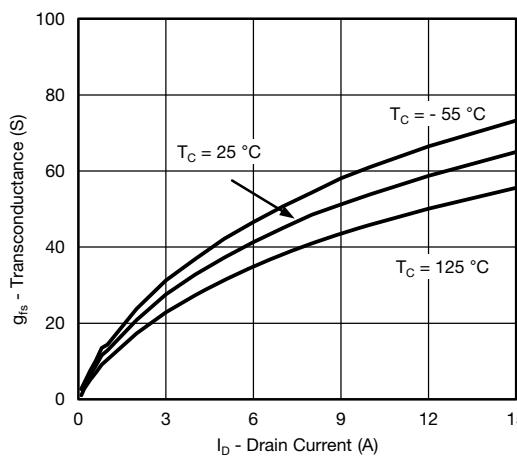
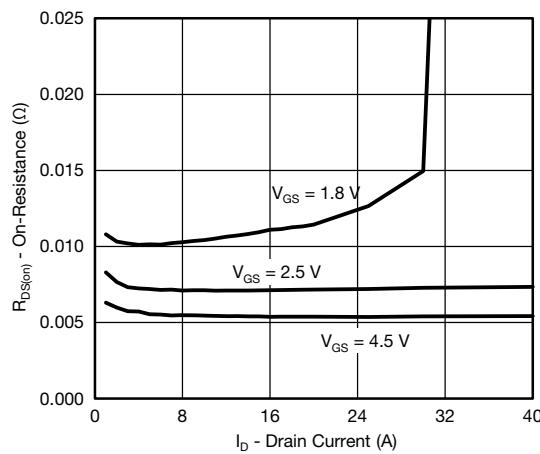
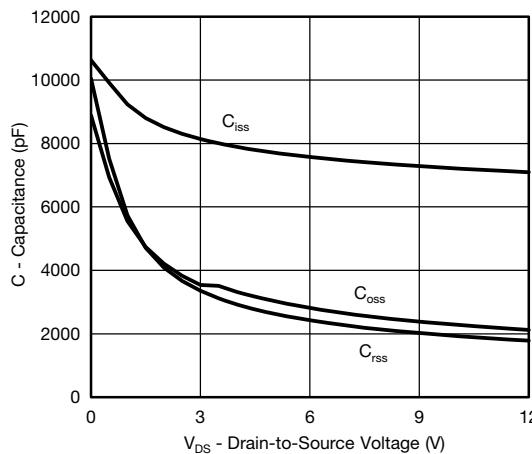
- Package limited
- Pulse test; pulse width ≤ 300 μ s, duty cycle ≤ 2 %
- When mounted on 1" square PCB (FR4 material)

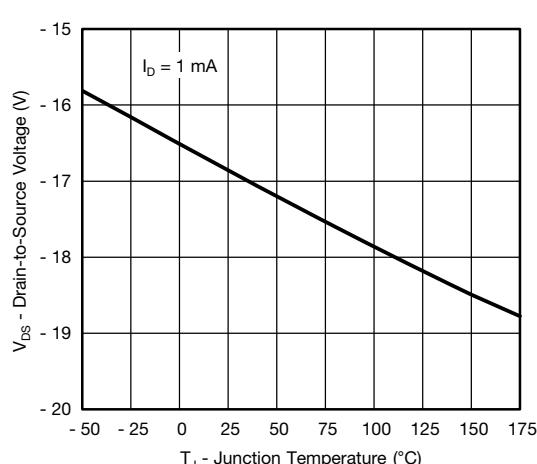
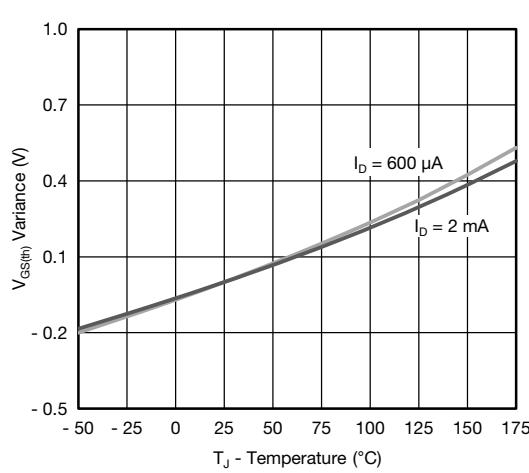
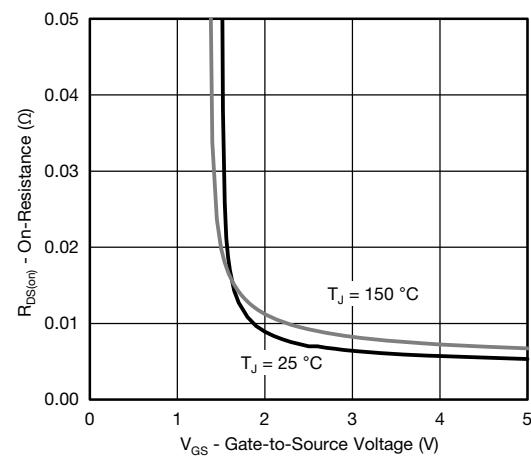
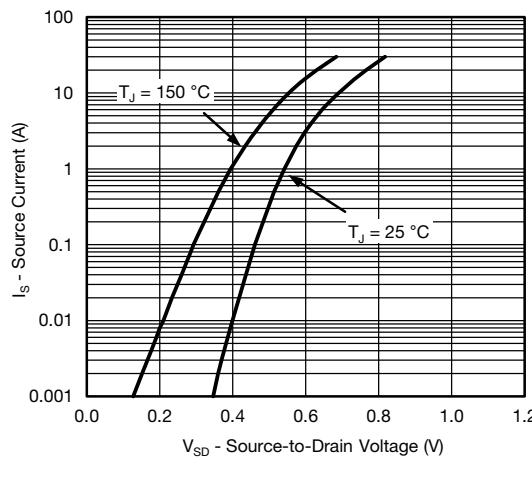
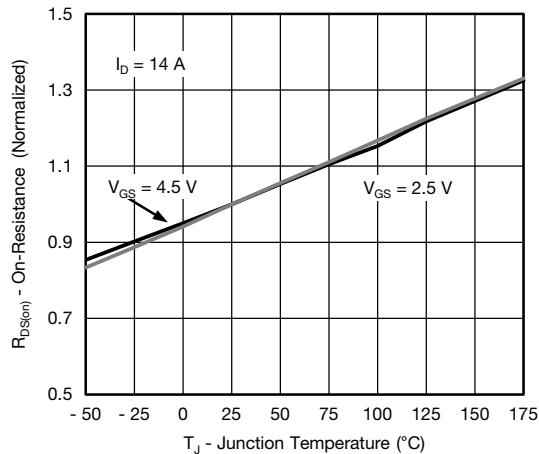
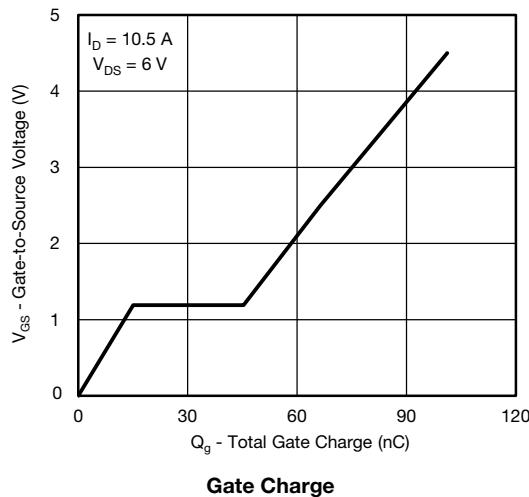
SPECIFICATIONS ($T_C = 25^\circ\text{C}$, unless otherwise noted)								
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT	
Static								
Drain-source breakdown voltage	V_{DS}	$V_{GS} = 0$, $I_D = -250 \mu\text{A}$		-12	-	-	V	
Gate-source threshold voltage	$V_{GS(\text{th})}$	$V_{DS} = V_{GS}$, $I_D = -250 \mu\text{A}$		-0.4	-0.6	-0.9		
Gate-source leakage	I_{GSS}	$V_{DS} = 0 \text{ V}$, $V_{GS} = \pm 8 \text{ V}$		-	-	± 100	nA	
Zero gate voltage drain current	I_{DSS}	$V_{GS} = 0 \text{ V}$	$V_{DS} = -12 \text{ V}$	-	-	-1	μA	
		$V_{GS} = 0 \text{ V}$	$V_{DS} = -12 \text{ V}$, $T_J = 125^\circ\text{C}$	-	-	-50		
		$V_{GS} = 0 \text{ V}$	$V_{DS} = -12 \text{ V}$, $T_J = 175^\circ\text{C}$	-	-	-150		
On-state drain current ^a	$I_{D(\text{on})}$	$V_{GS} = -4.5 \text{ V}$	$V_{DS} \geq -5 \text{ V}$	-30	-	-	A	
Drain-source on-state resistance ^a	$R_{DS(\text{on})}$	$V_{GS} = -4.5 \text{ V}$	$I_D = -14 \text{ A}$	-	0.00510	0.00832	Ω	
		$V_{GS} = -4.5 \text{ V}$	$I_D = -14 \text{ A}$, $T_J = 125^\circ\text{C}$	-	-	0.00900		
		$V_{GS} = -4.5 \text{ V}$	$I_D = -14 \text{ A}$, $T_J = 175^\circ\text{C}$	-	-	0.01100		
		$V_{GS} = -2.5 \text{ V}$	$I_D = -13 \text{ A}$	-	0.00650	0.01000		
		$V_{GS} = -1.8 \text{ V}$	$I_D = -12 \text{ A}$	-	0.00940	0.01430		
Forward transconductance ^a	g_{fs}	$V_{DS} = -6 \text{ V}$, $I_D = -10.5 \text{ A}$		-	54	-	S	
Dynamic^b								
Input capacitance	C_{iss}	$V_{GS} = 0 \text{ V}$	$V_{DS} = -6 \text{ V}$, $f = 1 \text{ MHz}$	-	7500	11 000	pF	
Output capacitance	C_{oss}			-	2800	4200		
Reverse transfer capacitance	C_{rss}			-	2400	3600		
Total gate charge ^c	Q_g	$V_{GS} = -4.5 \text{ V}$	$V_{DS} = -6 \text{ V}$, $I_D = -10.5 \text{ A}$	-	101	151	nC	
Gate-source charge ^c	Q_{gs}			-	15	-		
Gate-drain charge ^c	Q_{gd}			-	45	-		
Gate resistance	R_g	$f = 1 \text{ MHz}$		1.1	2.2	3.2	Ω	
Turn-on delay time ^c	$t_{d(\text{on})}$	$V_{DD} = -6 \text{ V}$, $R_L = 15 \Omega$ $I_D \cong -10.5 \text{ A}$, $V_{GEN} = -4.5 \text{ V}$, $R_g = 6 \Omega$		-	31	42	ns	
Rise time ^c	t_r			-	168	224		
Turn-off delay time ^c	$t_{d(\text{off})}$			-	310	412		
Fall time ^c	t_f			-	283	376		
Source-Drain Diode Ratings and Characteristics^b								
Pulsed current ^a	I_{SM}			-	-	-100	A	
Forward voltage	V_{SD}	$I_F = -10.5 \text{ A}$, $V_{GS} = 0$		-	-0.8	-1.2	V	

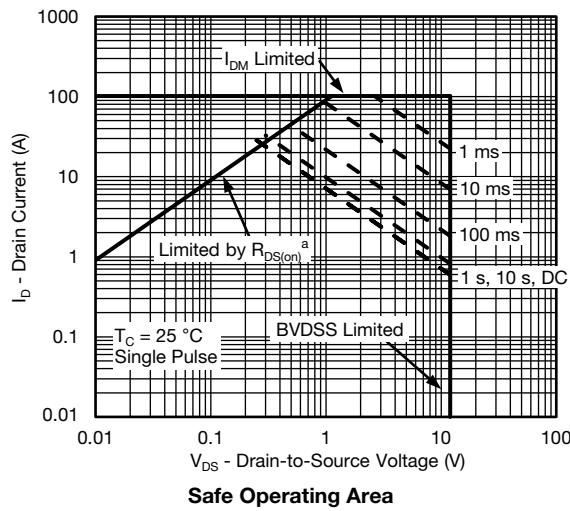
Notes

- a. Pulse test; pulse width $\leq 300 \mu\text{s}$, duty cycle $\leq 2\%$
- b. Guaranteed by design, not subject to production testing
- c. Independent of operating temperature

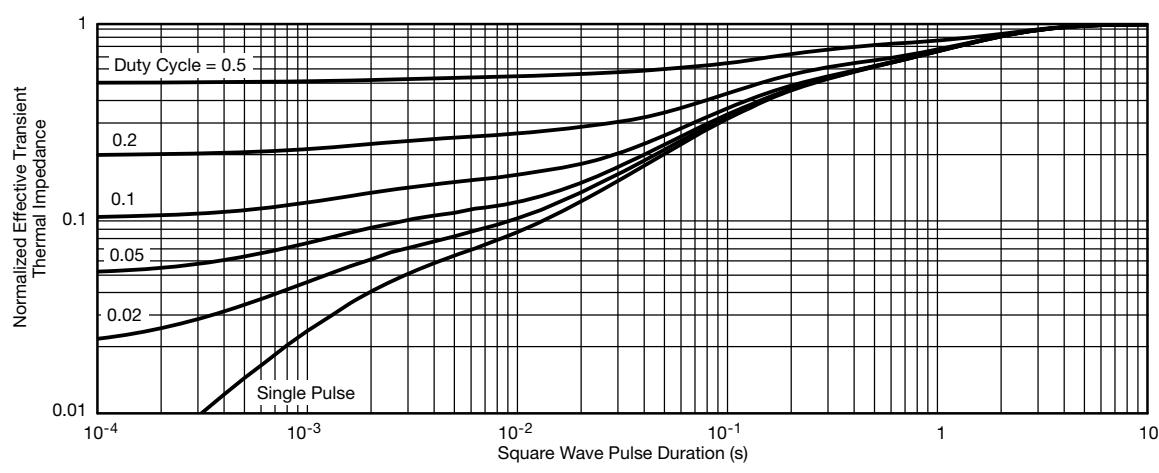
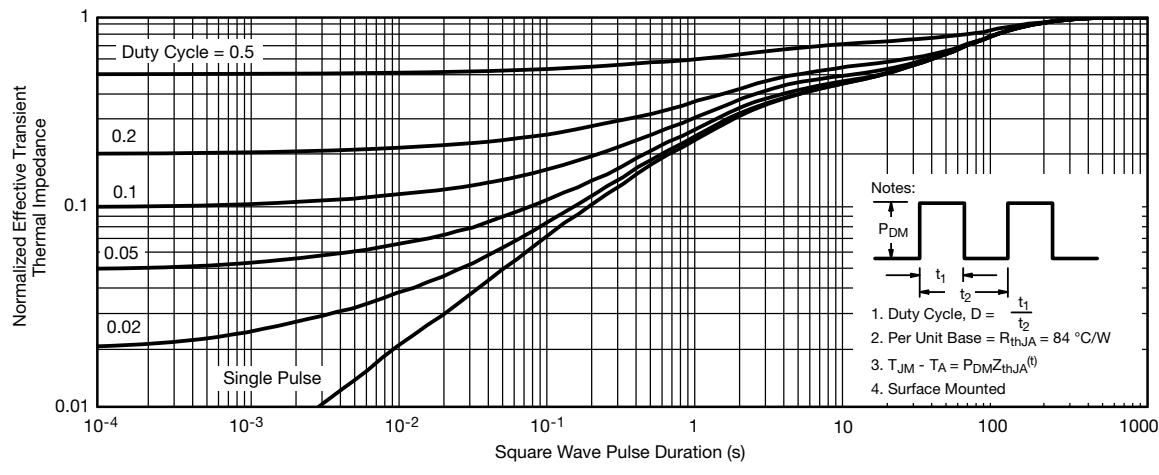
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$, unless otherwise noted)

Output Characteristics

Transfer Characteristics

Transfer Characteristics

Transconductance

On-Resistance vs. Drain Current

Capacitance

TYPICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$, unless otherwise noted)


THERMAL RATINGS ($T_A = 25^\circ\text{C}$, unless otherwise noted)

Note

a. $V_{GS} >$ minimum V_{GS} at which $R_{DS(on)}$ is specified

THERMAL RATINGS ($T_A = 25^\circ\text{C}$, unless otherwise noted)

Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25°C)
 - Normalized Transient Thermal Impedance Junction-to-Foot (25°C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions

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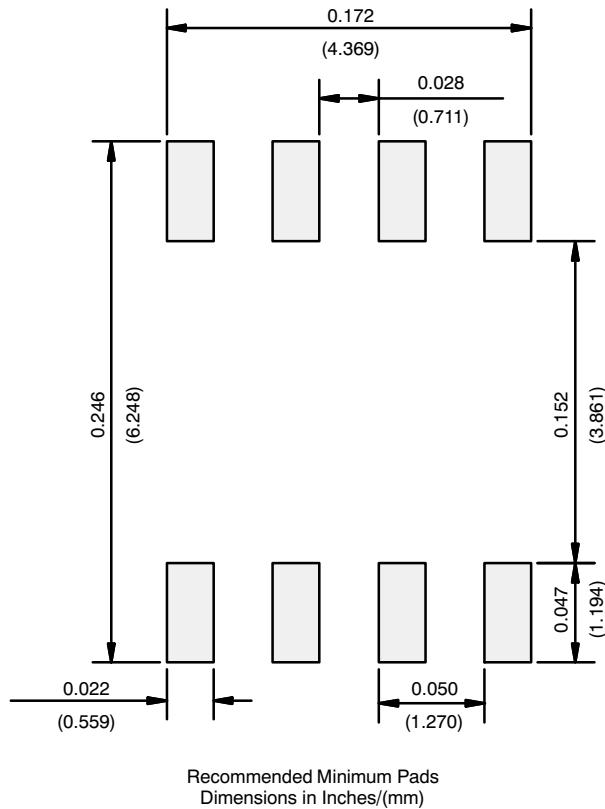
SOIC (NARROW): 8-LEAD

JEDEC Part Number: MS-012

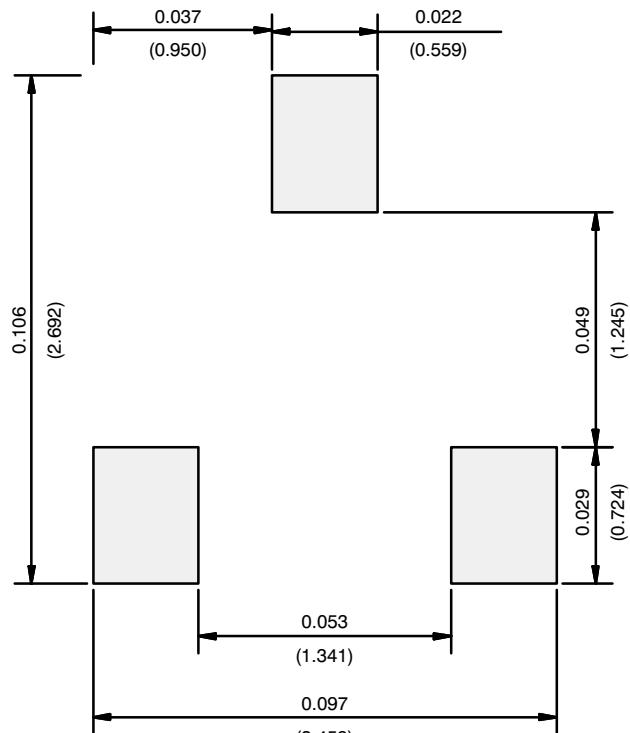


DIM	MILLIMETERS		INCHES	
	Min	Max	Min	Max
A	1.35	1.75	0.053	0.069
A ₁	0.10	0.20	0.004	0.008
B	0.35	0.51	0.014	0.020
C	0.19	0.25	0.0075	0.010
D	4.80	5.00	0.189	0.196
E	3.80	4.00	0.150	0.157
e	1.27 BSC		0.050 BSC	
H	5.80	6.20	0.228	0.244
h	0.25	0.50	0.010	0.020
L	0.50	0.93	0.020	0.037
q	0°	8°	0°	8°
S	0.44	0.64	0.018	0.026
ECN: C-06527-Rev. I, 11-Sep-06				
DWG: 5498				

RECOMMENDED MINIMUM PADS FOR SO-8



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RECOMMENDED MINIMUM PADS FOR SOT-23

Recommended Minimum Pads
Dimensions in Inches/(mm)

[Return to Index](#)

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